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March 2013



FAN73711 High-Current, High-Side Gate Drive IC

Features

- Floating Channel for Bootstrap Operation to +600 V
- 4 A / 4 A Sourcing/Sinking Current Driving Capability
- Common-Mode dv/dt Noise Canceling Circuit
- 3.3 V and 5 V Input Logic Compatible
- Output In-phase with Input Signal
- Under-Voltage Lockout for V_{BS}
- Built-In Shunt Regulator on V_{DD} and V_{BS}
- 8-Lead, Small Outline Package (SOP)

Applications

- High-Speed Gate Driver
- Sustain Switch Driver in PDP Application
- Energy Recovery Circuit Switch Driver in PDP Application
- High-Power Buck Converter
- Motor Drive Inverter

Description

The FAN73711 is a monolithic high-side gate-drive IC that can drive high-speed MOSFETs and IGBTs operating up to +600 V. It has a buffered output stage with all NMOS transistors designed for high pulse-current driving capability and minimum cross-conduction.

Fairchild's high-voltage process and common-mode noise canceling techniques provide stable operation of the high-side driver under high dv/dt noise circumstances. An advanced level-shift circuit offers high-side gate driver operation up to V_S=-9.8 V (typical) for V_{BS}=15 V. The UVLO circuit prevents malfunction when V_{BS} is lower than the specified threshold voltage.

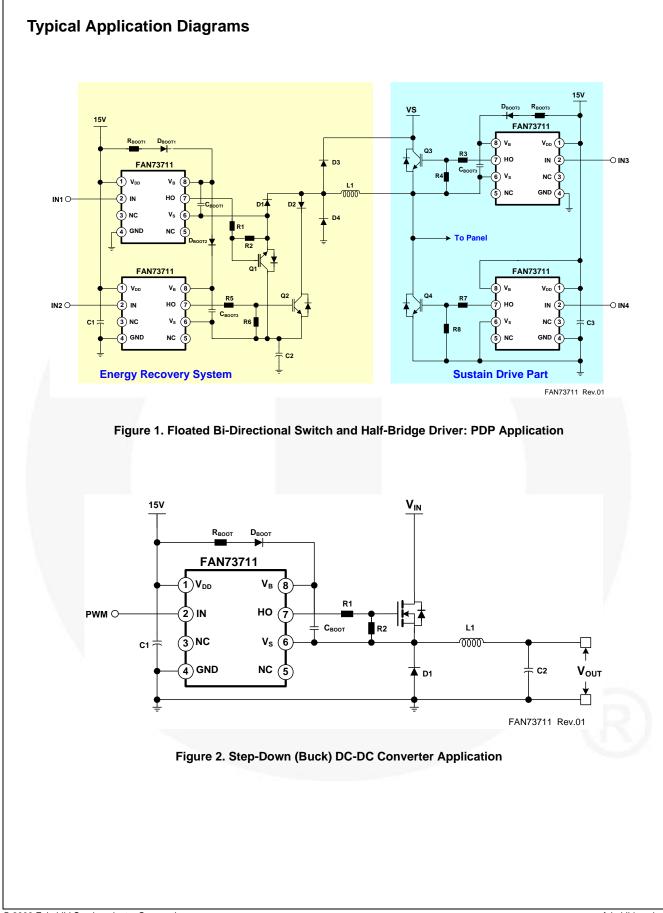
The high-current and low-output voltage-drop feature makes this device suitable as a sustain and energy-recovery circuit switch driver in plasma display panel, motor drive inverter, switching power supply, and high-power DC-DC converter applications.

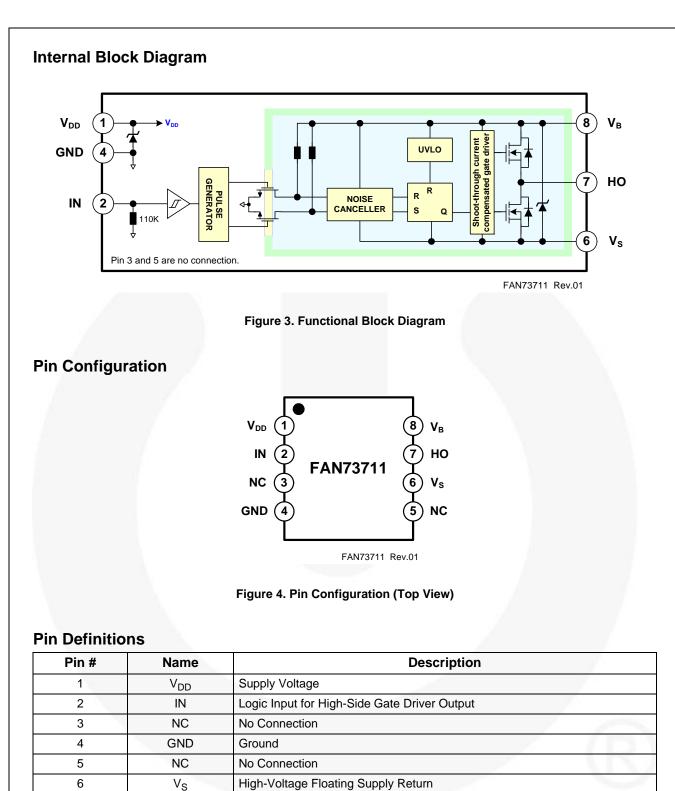
8-SOP

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Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method		
FAN73711MX	40°C ~ 125°C	8-SOP	Tape and Reel		





FAN73711 — High-Current, High-Side Gate Drive IC

HO

VB

7

8

High-Side Driver Output

High-Side Floating Supply

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Characteristics	Min.	Max.	Unit
VS	High-Side Floating Offset Voltage ⁽¹⁾	V _B -V _{SHUNT}	V _B +0.3	V
VB	High-Side Floating Supply Voltage	-0.3	625.0	V
V _{HO}	High-Side Floating Output Voltage	V _S -0.3	V _B +0.3	V
V _{DD}	Low-Side and Logic Supply Voltage ⁽¹⁾	-0.3	V _{SHUNT}	V
V _{IN}	Logic Input Voltage	-0.3	V _{DD} +0.3	V
dV _S /dt	Allowable Offset Voltage Slew Rate		± 50	V/ns
PD	Power Dissipation ^(2,3,4)		0.625	W
θ_{JA}	Thermal Resistance		200	°C/W
Т _Ј	Junction Temperature	-55	+150	°C
T _{STG}	Storage Temperature	-55	+150	°C

Notes:

- 1. This IC contains a shunt regulator on V_{DD} and V_{BS}. This supply pin should not be driven by a low-impedance voltage source greater than the V_{SHUNT} specified in the Electrical Characteristics section.
- 2. Mounted on 76.2 x 114.3 x 1.6 mm PCB (FR-4 glass epoxy material).
- Refer to the following standards: JESD51-2: Integral circuits thermal test method environmental conditions, natural convection, and JESD51-3: Low effective thermal conductivity test board for leaded surface-mount packages.
- 4. Do not exceed power dissipation (P_D) under any circumstances.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Unit	
V _B	High-Side Floating Supply Voltage	V _S +10	V _S +20	V	
V _S	High-Side Floating Supply Offset Voltage	6-V _{DD}	600	V	
V _{HO}	High-Side Output Voltage	V _S	V _B	V	
V _{IN}	Logic Input Voltage	GND	V _{DD}	V	
V _{DD}	Supply Voltage	10	20	V	
T _A	Operating Ambient Temperature	-40	+125	°C	

Electrical Characteristics

 $V_{BIAS}(V_{DD}, V_{BS})$ =15.0 V, T_A = 25°C, unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to GND. The V_O and I_O parameters are relative to V_S and are applicable to the respective output HO.

Symbol	Characteristics	Test Condition	Min.	Тур.	Max.	Unit
Power S	upply Section					<u></u>
I _{QDD}	Quiescent V _{DD} Supply Current	V _{IN} =0 V or 5 V		25	70	μΑ
I _{PDD}	Operating V _{DD} Supply Current	f _{IN} =20 kHz, No Load		35	100	μΑ
Bootstra	apped Supply Section			1		<u> </u>
V _{BSUV+}	V _{BS} Supply Under-Voltage Positive-Going Threshold Voltage	V _{BS} =Sweep	8.0	9.0	10.0	V
V _{BSUV-}	V _{BS} Supply Under-Voltage Negative-Going Threshold Voltage	V _{BS} =Sweep	7.3	8.3	9.3	V
V _{BSHYS}	V _{BS} Supply Under-Voltage Lockout Hysteresis Voltage	V _{BS} =Sweep		0.7		V
I _{LK}	Offset Supply Leakage Current	V _B =V _S =625 V			10	μΑ
I _{QBS}	Quiescent V _{BS} Supply Current	V _{IN} =0V or 5 V		60	120	μΑ
I _{PBS}	Operating V _{BS} Supply Current	C _{LOAD} =1000 pF, f _{IN} =20 kHz, rms Value		470	800	μΑ
Shunt R	egulator Section			1		J
V _{SHUNT}	V _{DD} and V _{BS} Shunt Regulator Clamping Voltage	V _{DD} =Sweep or V _{BS} =Sweep I _{SHUNT} =5 mA	21	23	25	V
Input Lo	gic Section					
V _{IH}	Logic "1" Input Voltage		2.5			V
VIL	Logic "0" Input Voltage				0.8	V
I _{IN+}	Logic Input High Bias Current	V _{IN} =5 V		40	65	μΑ
I _{IN-}	Logic Input Low Bias Current	V _{IN} =0 V			2	μΑ
R _{IN}	Input Pull-Down Resistance		90	110		KΩ
Gate Dri	ver Output Section					
V _{OH}	High Level Output Voltage (V _{BIAS} - V _O)	No Load			1.2	V
V _{OL}	Low Level Output Voltage	No Load			30	mV
I _{O+}	Output High, Short-Circuit Pulsed Current ⁽⁵⁾	V _{HO} =0 V, V _{IN} =5 V, PW ≤10 µs	3	4		Α
I _{O-}	Output Low, Short-Circuit Pulsed Current ⁽⁵⁾	V _{HO} =15 V,V _{IN} =0 V, PW ≤10 μs	3	4		Α
Vs	Allowable Negative V _S Pin Voltage for IN Signal Propagation to HO			-9.8	-7.0	V

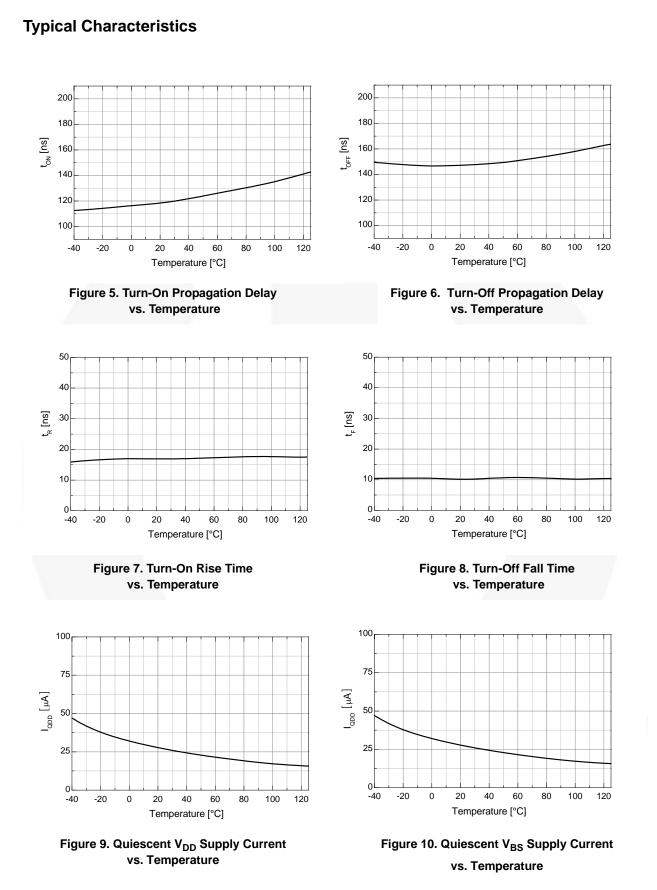
Note:

5. These parameters guaranteed by design.

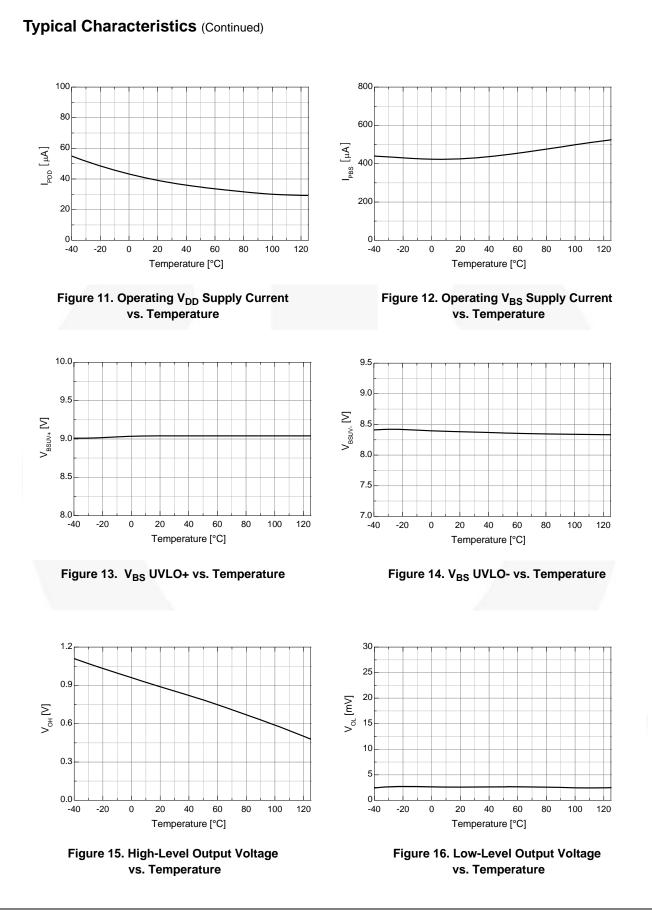
Dynamic Electrical Characteristics

 $V_{DD}{=}V_{BS}{=}15$ V, GND=0 V, $C_{LOAD}{=}1000$ pF, $T_{A}{=}25^{\circ}C$, unless otherwise specified.

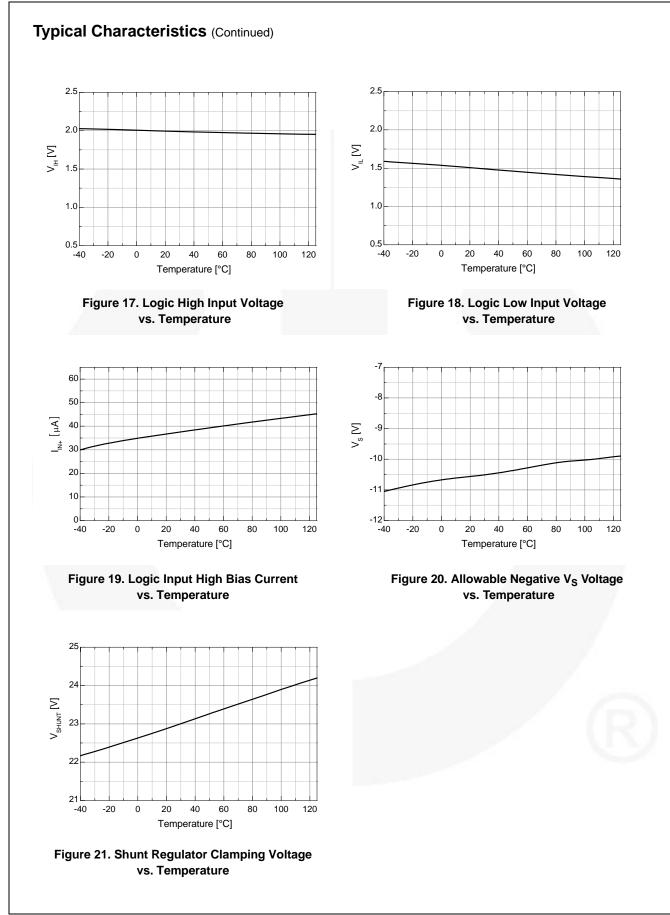
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
t _{on}	Turn-On Propagation Delay	V _S =0 V		150	210	ns
t _{off}	Turn-Off Propagation Delay	V _S =0 V		150	210	ns
t _r	Turn-On Rise Time			25	50	ns
t _f	Turn-Off Fall Time			15	40	ns



FAN73711 — High-Current, High-Side Gate Drive IC

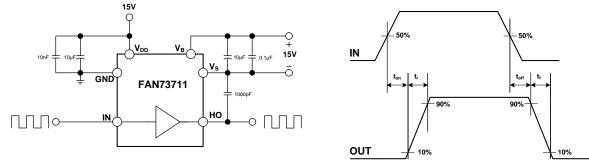


FAN73711 — High-Current, High-Side Gate Drive IC



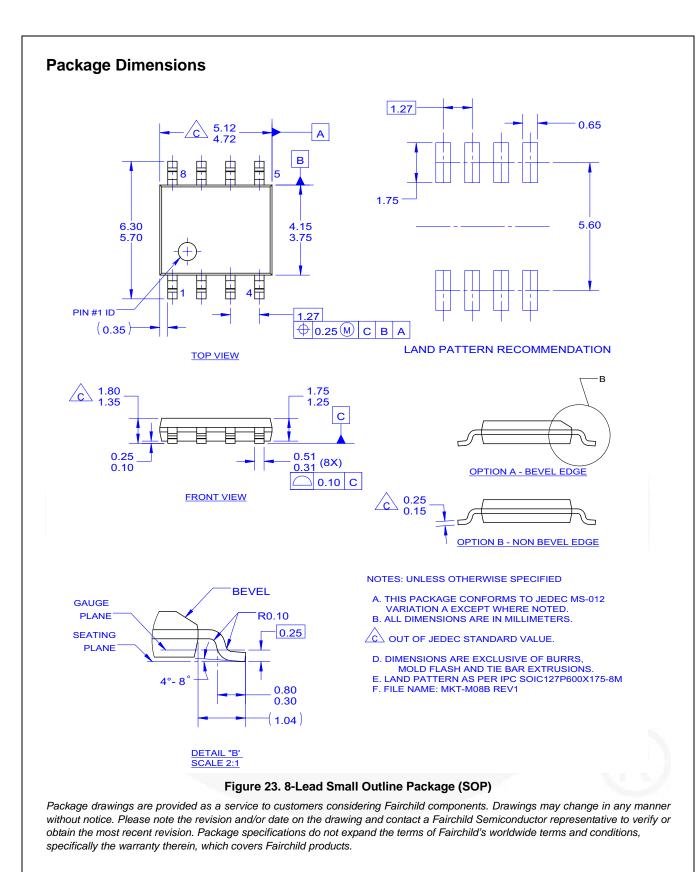
Switching Time Definitions

Timing Diagram



FAN73711 Rev.01





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FAN73711 — High-Current, High-Side Gate Drive

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